



1	I _{cc}	mA	-	300
		mV	150	1100
		mV	300	600
TX_fault /LOS (TTL)	VOH	V	2.0	V _{cc}
	VOL	V	0	0.8
TX_disable (TTL)	VOH	V	2.0	V _{cc}
	VOL	V	0	0.8
	P _o	dBm	-9.5	-3
	λ _c	nm	830	860
	EX	dB	9	
(RMS)	Δλ	nm		4
2	TJ	UI		0.284
3	RIN	dB/Hz		-120
		GE		
/	Trise/Tfall	ps		260
	-	dB		1
	P _{off}	dBm		-45
	λ _c	nm	770	870
4	S	dBm		-18
	Pin	dBm	0	
		dBm		-18
			-35	

		dB	0.5		5
Note1. Note2. Note3. RIN 12dB Note4. PRBS 1.25Gb/s EX=10dB					
